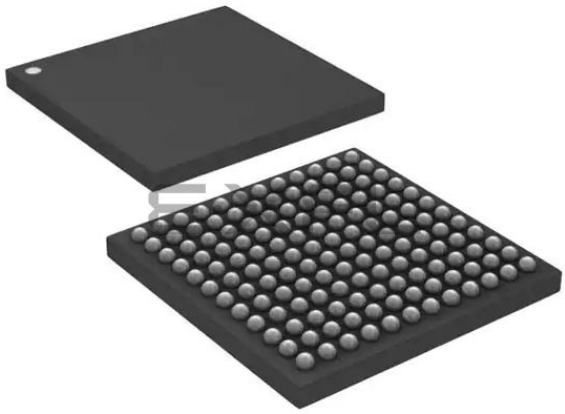
Lattice Semiconductor Corporation - LC4064ZE-5MN144I Datasheet



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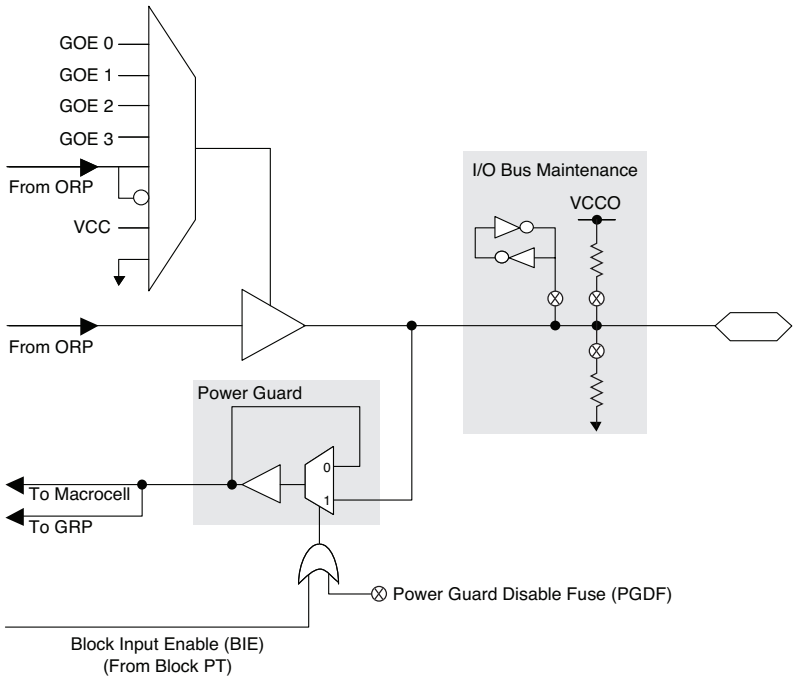
Understanding Embedded - CPLDs (Complex Programmable Logic Devices)

Embedded - CPLDs, or Complex Programmable Logic Devices, are highly versatile digital logic devices used in electronic systems. These programmable components are designed to perform complex logical operations and can be customized for specific applications. Unlike fixed-function ICs, CPLDs offer the flexibility to reprogram their configuration, making them an ideal choice for various embedded systems. They consist of a set of logic gates and programmable interconnects, allowing designers to implement complex logic circuits without needing custom hardware.

Applications of Embedded - CPLDs

Details	
Product Status	Active
Programmable Type	In System Programmable
Delay Time tpd(1) Max	5.8 ns
Voltage Supply - Internal	1.7V ~ 1.9V
Number of Logic Elements/Blocks	4
Number of Macrocells	64
Number of Gates	-
Number of I/O	64
Operating Temperature	-40°C ~ 105°C (TJ)
Mounting Type	Surface Mount
Package / Case	144-TFBGA, CSPBGA
Supplier Device Package	144-CSBGA (7x7)
Purchase URL	https://www.e-xfl.com/product-detail/lattice-semiconductor/lc4064ze-5mn144i

Figure 8. I/O Cell



Each output supports a variety of output standards dependent on the V_{CCO} supplied to its I/O bank. Outputs can also be configured for open drain operation. Each input can be programmed to support a variety of standards, independent of the V_{CCO} supplied to its I/O bank. The I/O standards supported are:

- LVTTL
- LVCMOS 3.3
- LVCMOS 2.5
- LVCMOS 1.8
- LVCMOS 1.5
- 3.3V PCI Compatible

All of the I/Os and dedicated inputs have the capability to provide a bus-keeper latch, pull-up resistor or pull-down resistor selectable on a “per-pin” basis. A fourth option is to provide none of these. The default in both hardware and software is such that when the device is erased or if the user does not specify, the input structure is configured to be a Pull-down Resistor.

Each ispMACH 4000ZE device I/O has an individually programmable output slew rate control bit. Each output can be individually configured for fast slew or slow slew. The typical edge rate difference between fast and slow slew setting is 20%. For high-speed designs with long, unterminated traces, the slow-slew rate will introduce fewer reflections, less noise and keep ground bounce to a minimum. For designs with short traces or well terminated lines, the fast slew rate can be used to achieve the highest speed.

The ispMACH 4000ZE family has an always on, 200mV typical hysteresis for each input operational at 3.3V and 2.5V. This provides improved noise immunity for slow transitioning signals.

Power Guard

Power Guard allows easier achievement of standby current in the system. As shown in Figure 9, this feature consists of an enabling multiplexer between an I/O pin and input buffer, and its associated circuitry inside the device.

If the enable signal (E) is held low, all inputs (D) can be optionally isolated (guarded), such that, if any of these were toggled, it would not cause any toggle on internal pins (Q), thus, a toggling I/O pin will not cause any internal dynamic power consumption.

Some Simple Use Scenarios

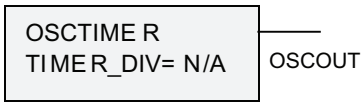
The following diagrams show a few simple examples that omit optional signals for the OSCTIMER block:

A. An oscillator giving 5MHz nominal clock

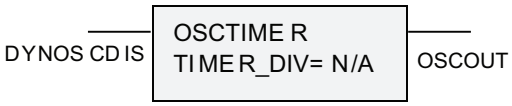
B. An oscillator that can be disabled with an external signal (5MHz nominal clock)

C. An oscillator giving approximately 5 Hz nominal clock (TIMER_DIV = 2^{20} (1,048,576))

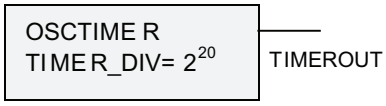
D. An oscillator giving two output clocks: ~5MHz and ~5KHz (TIMER_DIV= 2^{10} (1,024))



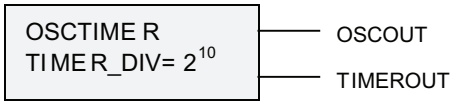
(A) A simple 5MHz oscillator.



(B) An oscillator with dynamic disable.



(C) A simple 5Hz oscillator.



(D) Oscillator with two outputs (5MHz and 5KHz).

OSCTIMER Integration With CPLD Fabric

The OSCTIMER is integrated into the CPLD fabric using the Global Routing Pool (GRP). The macrocell (MC) feedback path for two macrocells is augmented with a programmable multiplexer, as shown in Figure 15. The OSCTIMER outputs (OSCOUT and TIMEROUT) can optionally drive the GRP lines, whereas the macrocell outputs can drive the optional OSCTIMER inputs TIMERRES and DYNOSCDIS.

Figure 15. OSCTIMER Integration With CPLD Fabric

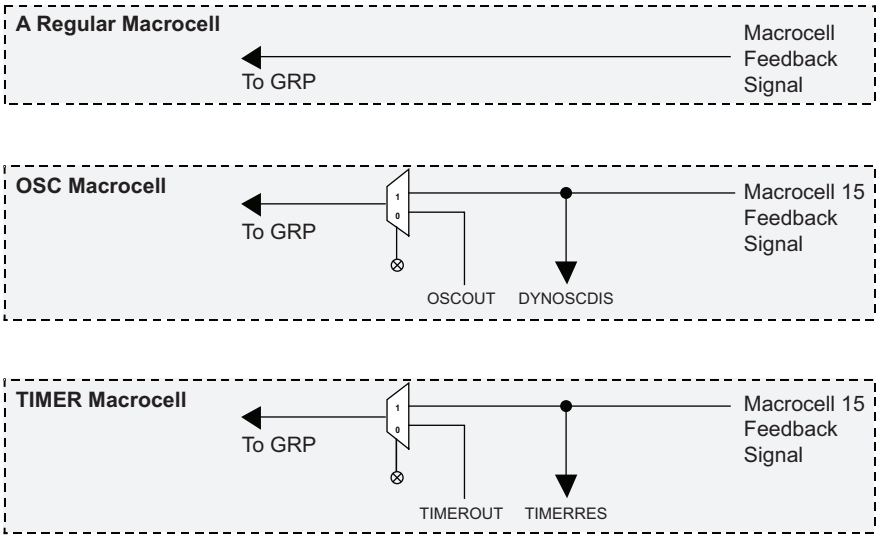


Table 12 shows how these two MCs are designated in each of the ispMACH4000ZE device.

I/O Recommended Operating Conditions

Standard	V_{CCO} (V)[1]	
	Min.	Max.
LVTTL	3.0	3.6
LVCMOS 3.3	3.0	3.6
Extended LVCMOS 3.3	2.7	3.6
LVCMOS 2.5	2.3	2.7
LVCMOS 1.8	1.65	1.95
LVCMOS 1.5	1.4	1.6
PCI 3.3	3.0	3.6

1. Typical values for V_{CCO} are the average of the min. and max. values.

DC Electrical Characteristics

Over Recommended Operating Conditions

Symbol	Parameter	Condition	Min.	Typ.	Max.	Units
I_{IL}, I_{IH}[1, 2]	Input Leakage Current	$0 \le V_{IN} < V_{CCO}$	—	0.5	1	µA
I_{IH}[1]	Input High Leakage Current	$V_{CCO} < V_{IN} \le 5.5V$	—	—	10	µA
I_{PU}	I/O Weak Pull-up Resistor Current	$0 \le V_{IN} \le 0.7V_{CCO}$	-20	—	-150	µA
I_{PD}	I/O Weak Pull-down Resistor Current	V_{IL} (MAX) $\le V_{IN} \le V_{IH}$ (MAX)	30	—	150	µA
I_{BHLS}	Bus Hold Low Sustaining Current	$V_{IN} = V_{IL}$ (MAX)	30	—	—	µA
I_{BHHS}	Bus Hold High Sustaining Current	$V_{IN} = 0.7\ V_{CCO}$	-20	—	—	µA
I_{BHLO}	Bus Hold Low Overdrive Current	$0V \le V_{IN} \le V_{BHT}$	—	—	150	µA
I_{BHHO}	Bus Hold High Overdrive Current	$V_{BHT} \le V_{IN} \le V_{CCO}$	—	—	-150	µA
V_{BHT}	Bus Hold Trip Points	—	V_{CCO} * 0.35	—	V_{CCO} * 0.65	V
C_1	I/O Capacitance[3]	V_{CCO} = 3.3V, 2.5V, 1.8V, 1.5V	—	8	—	pf
		V_{CC} = 1.8V, V_{IO} = 0 to V_{IH} (MAX)	—		—	
C_2	Clock Capacitance[3]	V_{CCO} = 3.3V, 2.5V, 1.8V, 1.5V	—	6	—	pf
		V_{CC} = 1.8V, V_{IO} = 0 to V_{IH} (MAX)	—		—	
C_3	Global Input Capacitance[3]	V_{CCO} = 3.3V, 2.5V, 1.8V, 1.5V	—	6	—	pf
		V_{CC} = 1.8V, V_{IO} = 0 to V_{IH} (MAX)	—		—	

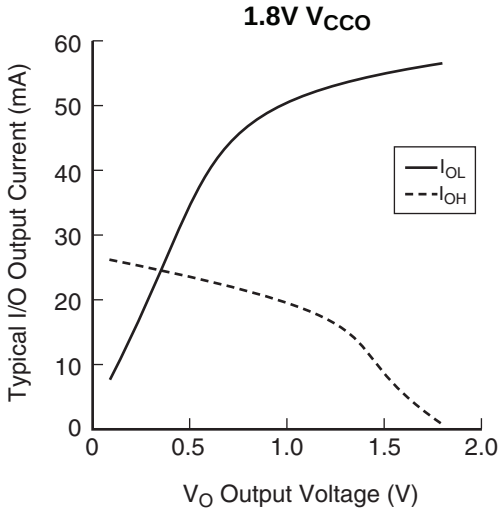
1. Input or I/O leakage current is measured with the pin configured as an input or as an I/O with the output driver tristated. It is not measured with the output driver active. Bus maintenance circuits are disabled.
2. I_{IH} excursions of up to 1.5µA maximum per pin above the spec limit may be observed for certain voltage conditions on no more than 10% of the device's I/O pins.
3. Measured T_A = 25°C, f = 1.0MHz.

I/O DC Electrical Characteristics

Over Recommended Operating Conditions

Standard	V_{IL}		V_{IH}		V_{OL} Max (V)	V_{OH} Min (V)	I_{OL}[1] (mA)	I_{OH}[1] (mA)
	Min (V)	Max (V)	Min (V)	Max (V)				
LVTTL	-0.3	0.80	2.0	5.5	0.40	V_{CCO} - 0.40	8.0	-4.0
					0.20	V_{CCO} - 0.20	0.1	-0.1
LVCMOS 3.3	-0.3	0.80	2.0	5.5	0.40	V_{CCO} - 0.40	8.0	-4.0
					0.20	V_{CCO} - 0.20	0.1	-0.1
LVCMOS 2.5	-0.3	0.70	1.70	3.6	0.40	V_{CCO} - 0.40	8.0	-4.0
					0.20	V_{CCO} - 0.20	0.1	-0.1
LVCMOS 1.8	-0.3	0.35 * V_{CC}	0.65 * V_{CC}	3.6	0.40	V_{CCO} - 0.45	2.0	-2.0
					0.20	V_{CCO} - 0.20	0.1	-0.1
LVCMOS 1.5[2]	-0.3	0.35 * V_{CC}	0.65 * V_{CC}	3.6	0.40	V_{CCO} - 0.45	2.0	-2.0
					0.20	V_{CCO} - 0.20	0.1	-0.1
PCI 3.3	-0.3	0.3 * 3.3 * (V_{CC} / 1.8)	0.5 * 3.3 * (V_{CC} / 1.8)	5.5	0.1 V_{CCO}	0.9 V_{CCO}	1.5	-0.5

1. The average DC current drawn by I/Os between adjacent bank GND connections, or between the last GND in an I/O bank and the end of the I/O bank, as shown in the logic signals connection table, shall not exceed *n**8mA. Where *n* is the number of I/Os between bank GND connections or between the last GND in a bank and the end of a bank.
2. For 1.5V inputs, there may be an additional DC current drawn from V_{CC}, if the ispMACH 4000ZE V_{CC} and the V_{CC} of the driving device (V_{CC}d-d; that determines steady state V_{IH}) are in the extreme range of their specifications. Typically, DC current drawn from V_{CC} will be 2µA per input.



ispMACH 4000ZE External Switching Characteristics

Over Recommended Operating Conditions

Parameter	Description[1, 2]	LC4032ZE		LC4064ZE		All Devices				Units
		-4		-4		-5		-7		
		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
t_{PD}	20-PT combinatorial propagation delay	—	4.4	—	4.7	—	5.8	—	7.5	ns
t_S	GLB register setup time before clock	2.2	—	2.5	—	2.9	—	4.5	—	ns
t_{ST}	GLB register setup time before clock with T-type register	2.4	—	2.7	—	3.1	—	4.7	—	ns
t_{SIR}	GLB register setup time before clock, input register path	1.0	—	1.1	—	1.3	—	1.4	—	ns
t_{SIRZ}	GLB register setup time before clock with zero hold	2.0	—	2.1	—	2.9	—	4.0	—	ns
t_H	GLB register hold time after clock	0.0	—	0.0	—	0.0	—	0.0	—	ns
t_{HT}	GLB register hold time after clock with T-type register	0.0	—	0.0	—	0.0	—	0.0	—	ns
t_{HIR}	GLB register hold time after clock, input register path	1.0	—	1.0	—	1.3	—	1.3	—	ns
t_{HIRZ}	GLB register hold time after clock, input register path with zero hold	0.0	—	0.0	—	0.0	—	0.0	—	ns
t_{CO}	GLB register clock-to-output delay	—	3.0	—	3.2	—	3.8	—	4.5	ns
t_R	External reset pin to output delay	—	5.0	—	6.0	—	7.5	—	9.0	ns
t_{RW}	External reset pulse duration	1.5	—	1.7	—	2.0	—	4.0	—	ns
$t_{PTOE/DIS}$	Input to output local product term output enable/disable	—	7.0	—	8.0	—	8.2	—	9.0	ns
$t_{GPTOE/DIS}$	Input to output global product term output enable/disable	—	6.5	—	7.0	—	10.0	—	10.5	ns
$t_{GOE/DIS}$	Global OE input to output enable/disable	—	4.5	—	4.5	—	5.5	—	7.0	ns
t_{CW}	Global clock width, high or low	1.0	—	1.5	—	1.8	—	2.8	—	ns
t_{GW}	Global gate width low (for low transparent) or high (for high transparent)	1.0	—	1.5	—	1.8	—	2.8	—	ns
t_{WIR}	Input register clock width, high or low	1.0	—	1.5	—	1.8	—	2.8	—	ns
f_{MAX} (Int.)[3]	Clock frequency with internal feedback	—	260	—	241	—	200	—	172	MHz
f_{MAX} (Ext.)	clock frequency with external feedback, $[1 / (t_S + t_{CO})]$	—	192	—	175	—	149	—	111	MHz

1. Timing numbers are based on default LVCMOS 1.8 I/O buffers. Use timing adjusters provided to calculate other standards.
2. Measured using standard switching GRP loading of 1 and 1 output switching.
3. Standard 16-bit counter using GRP feedback.

Timing v.0.8

ispMACH 4000ZE Internal Timing Parameters

Over Recommended Operating Conditions

Parameter	Description	LC4032ZE -4 Min.	LC4032ZE -4 Max.	LC4064ZE -4 Min.	LC4064ZE -4 Max.	Units
In/Out Delays						
t_{IN}	Input Buffer Delay	—	0.85	—	0.90	ns
t_{GCLK_IN}	Global Clock Input Buffer Delay	—	1.60	—	1.60	ns
t_{GOE}	Global OE Pin Delay	—	2.25	—	2.25	ns
t_{BUF}	Delay through Output Buffer	—	0.75	—	0.90	ns
t_{EN}	Output Enable Time	—	2.25	—	2.25	ns
t_{DIS}	Output Disable Time	—	1.35	—	1.35	ns
t_{PGSU}	Input Power Guard Setup Time	—	3.30	—	3.55	ns
t_{PGH}	Input Power Guard Hold Time	—	0.00	—	0.00	ns
t_{PGPW}	Input Power Guard BIE Minimum Pulse Width	—	5.00	—	5.00	ns
t_{PGRT}	Input Power Guard Recovery Time Following BIE Dissertation	—	5.00	—	5.00	ns
Routing Delays						
t_{ROUTE}	Delay through GRP	—	1.60	—	1.70	ns
t_{PDi}	Macrocell Propagation Delay	—	0.25	—	0.25	ns
t_{MCELL}	Macrocell Delay	—	0.65	—	0.65	ns
t_{INREG}	Input Buffer to Macrocell Register Delay	—	0.90	—	1.00	ns
t_{FBK}	Internal Feedback Delay	—	0.55	—	0.55	ns
t_{ORP}	Output Routing Pool Delay	—	0.30	—	0.30	ns
Register/Latch Delays						
t_{S}	D-Register Setup Time (Global Clock)	0.70	—	0.85	—	ns
t_{S_PT}	D-Register Setup Time (Product Term Clock)	1.25	—	1.85	—	ns
t_{H}	D-Register Hold Time	1.50	—	1.65	—	ns
t_{ST}	T-Register Setup Time (Global Clock)	0.90	—	1.05	—	ns
t_{ST_PT}	T-register Setup Time (Product Term Clock)	1.45	—	1.65	—	ns
t_{HT}	T-Resister Hold Time	1.50	—	1.65	—	ns
t_{SIR}	D-Input Register Setup Time (Global Clock)	0.85	—	0.80	—	ns
t_{SIR_PT}	D-Input Register Setup Time (Product Term Clock)	1.45	—	1.45	—	ns
t_{HIR}	D-Input Register Hold Time (Global Clock)	1.15	—	1.30	—	ns
t_{HIR_PT}	D-Input Register Hold Time (Product Term Clock)	0.90	—	1.10	—	ns
t_{COi}	Register Clock to Output/Feedback MUX Time	—	0.35	—	0.40	ns
t_{CES}	Clock Enable Setup Time	1.00	—	2.00	—	ns
t_{CEH}	Clock Enable Hold Time	0.00	—	0.00	—	ns
t_{SL}	Latch Setup Time (Global Clock)	0.70	—	0.95	—	ns
t_{SL_PT}	Latch Setup Time (Product Term Clock)	1.45	—	1.85	—	ns
t_{HL}	Latch Hold Time	1.40	—	1.80	—	ns
t_{GOi}	Latch Gate to Output/Feedback MUX Time	—	0.40	—	0.35	ns
t_{PDLi}	Propagation Delay through Transparent Latch to Output/ Feedback MUX	—	0.30	—	0.25	ns
t_{SRi}	Asynchronous Reset or Set to Output/Feedback MUX Delay	—	0.30	—	0.30	ns

ispMACH 4000ZE Internal Timing Parameters (Cont.)

Over Recommended Operating Conditions

Parameter	Description		LC4032ZE -4 Min.	LC4032ZE -4 Max.	LC4064ZE -4 Min.	LC4064ZE -4 Max.	Units
t_{SRR}	Asynchronous Reset or Set Recovery Delay		—	2.00	—	1.70	ns
Control Delays							
t_{BCLK}	GLB PT Clock Delay		—	1.20	—	1.30	ns
t_{PTCLK}	Macrocell PT Clock Delay		—	1.40	—	1.50	ns
t_{BSR}	Block PT Set/Reset Delay		—	1.10	—	1.85	ns
t_{PTSR}	Macrocell PT Set/Reset Delay		—	1.20	—	1.90	ns
t_{BIE}	Power Guard Block Input Enable Delay		—	1.60	—	1.70	ns
t_{PTOE}	Macrocell PT OE Delay		—	2.30	—	3.15	ns
t_{GPTOE}	Global PT OE Delay		—	1.80	—	2.15	ns
Internal Oscillator							
t_{OSCSU}	Oscillator DYNOSCDIS Setup Time		5.00	—	5.00	—	ns
t_{OSCH}	Oscillator DYNOSCDIS Hold Time		5.00	—	5.00	—	ns
t_{OSCEN}	Oscillator OSCOUT Enable Time (To Stable)		—	5.00	—	5.00	ns
t_{OSCOD}	Oscillator Output Delay		—	4.00	—	4.00	ns
t_{OSCNOM}	Oscillator OSCOUT Nominal Frequency			5.00		5.00	MHz
t_{OSCvar}	Oscillator Variation of Nominal Frequency		—	30	—	30	%
$t_{TMRCO20}$	Oscillator TIMEROUT Clock (Negative Edge) to Out (20-Bit Divider)		—	12.50	—	12.50	ns
$t_{TMRCO10}$	Oscillator TIMEROUT Clock (Negative Edge) to Out (10-Bit Divider)		—	7.50	—	7.50	ns
t_{TMRCO7}	Oscillator TIMEROUT Clock (Negative Edge) to Out (7-Bit Divider)		—	6.00	—	6.00	ns
$t_{TMRRSTO}$	Oscillator TIMEROUT Reset to Out (Going Low)		—	5.00	—	5.00	ns
t_{TMRRR}	Oscillator TIMEROUT Asynchronous Reset Recovery Delay		—	4.00	—	4.00	ns
$t_{TMRRSTPW}$	Oscillator TIMEROUT Reset Minimum Pulse Width		3.00	—	3.00	—	ns
Optional Delay Adjusters		**Base Parameter**					
t_{INDIO}	Input Register Delay	t_{INREG}	—	1.00	—	1.00	ns
t_{EXP}	Product Term Expander Delay	t_{MCELL}	—	0.40	—	0.40	ns
t_{BLA}	Additional Block Loading Adders	t_{ROUTE}	—	0.04	—	0.05	ns
t_{IOI} Input Buffer Delays							
LVTTL_in	Using LVTTL Standard with Hysteresis	t_{IN}, t_{GCLK_IN}, t_{GOE}	—	0.60	—	0.60	ns
LVCMOS15_in	Using LVCMOS 1.5 Standard	t_{IN}, t_{GCLK_IN}, t_{GOE}	—	0.20	—	0.20	ns
LVCMOS18_in	Using LVCMOS 1.8 Standard	t_{IN}, t_{GCLK_IN}, t_{GOE}	—	0.00	—	0.00	ns
LVCMOS25_in	Using LVCMOS 2.5 Standard with Hysteresis	t_{IN}, t_{GCLK_IN}, t_{GOE}	—	0.80	—	0.80	ns
LVCMOS33_in	Using LVCMOS 3.3 Standard with Hysteresis	t_{IN}, t_{GCLK_IN}, t_{GOE}	—	0.80	—	0.80	ns
PCI_in	Using PCI Compatible Input with Hysteresis	t_{IN}, t_{GCLK_IN}, t_{GOE}	—	0.80	—	0.80	ns
t_{IOO} Output Buffer Delays							
LVTTL_out	Output Configured as TTL Buffer	t_{EN}, t_{DIS}, t_{BUF}	—	0.20	—	0.20	ns

ispMACH 4000ZE Internal Timing Parameters (Cont.)

Over Recommended Operating Conditions

Parameter	Description	All Devices				Units
		-5		-7		
		Min.	Max.	Min.	Max.	
In/Out Delays						
t_{IN}	Input Buffer Delay	—	1.05	—	1.90	ns
t_{GCLK_IN}	Global Clock Input Buffer Delay	—	1.95	—	2.15	ns
t_{GOE}	Global OE Pin Delay	—	3.00	—	4.30	ns
t_{BUF}	Delay through Output Buffer	—	1.10	—	1.30	ns
t_{EN}	Output Enable Time	—	2.50	—	2.70	ns
t_{DIS}	Output Disable Time	—	2.50	—	2.70	ns
t_{PGSU}	Input Power Guard Setup Time	—	4.30	—	5.60	ns
t_{PGH}	Input Power Guard Hold Time	—	0.00	—	0.00	ns
t_{PGPW}	Input Power Guard BIE Minimum Pulse Width	—	6.00	—	8.00	ns
t_{PGRT}	Input Power Guard Recovery Time Following BIE Dis-sertation	—	5.00	—	7.00	ns
Routing Delays						
t_{ROUTE}	Delay through GRP	—	2.25	—	2.50	ns
t_{PDi}	Macrocell Propagation Delay	—	0.45	—	0.50	ns
t_{MCELL}	Macrocell Delay	—	0.65	—	1.00	ns
t_{INREG}	Input Buffer to Macrocell Register Delay	—	1.00	—	1.00	ns
t_{FBK}	Internal Feedback Delay	—	0.75	—	0.30	ns
t_{ORP}	Output Routing Pool Delay	—	0.30	—	0.30	ns
Register/Latch Delays						
t_S	D-Register Setup Time (Global Clock)	0.90	—	1.25	—	ns
t_{S_PT}	D-Register Setup Time (Product Term Clock)	2.00	—	2.35	—	ns
t_H	D-Register Hold Time	2.00	—	3.25	—	ns
t_{ST}	T-Register Setup Time (Global Clock)	1.10	—	1.45	—	ns
t_{ST_PT}	T-register Setup Time (Product Term Clock)	2.20	—	2.65	—	ns
t_{HT}	T-Resister Hold Time	2.00	—	3.25	—	ns
t_{SIR}	D-Input Register Setup Time (Global Clock)	1.20	—	0.65	—	ns
t_{SIR_PT}	D-Input Register Setup Time (Product Term Clock)	1.45	—	1.45	—	ns
t_{HIR}	D-Input Register Hold Time (Global Clock)	1.40	—	2.05	—	ns
t_{HIR_PT}	D-Input Register Hold Time (Product Term Clock)	1.10	—	1.20	—	ns
t_{COi}	Register Clock to Output/Feedback MUX Time	—	0.45	—	0.75	ns
t_{CES}	Clock Enable Setup Time	2.00	—	2.00	—	ns
t_{CEH}	Clock Enable Hold Time	0.00	—	0.00	—	ns
t_{SL}	Latch Setup Time (Global Clock)	0.90	—	1.55	—	ns
t_{SL_PT}	Latch Setup Time (Product Term Clock)	2.00	—	2.05	—	ns
t_{HL}	Latch Hold Time	2.00	—	1.17	—	ns
t_{GOi}	Latch Gate to Output/Feedback MUX Time	—	0.35	—	0.33	ns
t_{PDLi}	Propagation Delay through Transparent Latch to Output/ Feedback MUX	—	0.25	—	0.25	ns
t_{SRi}	Asynchronous Reset or Set to Output/Feedback MUX Delay	—	0.95	—	0.28	ns

ispMACH 4000ZE Internal Timing Parameters (Cont.)

Over Recommended Operating Conditions

Parameter	Description		All Devices				Units
			-5		-7		
			Min.	Max.	Min.	Max.	
LVCMOS15_out	Output Configured as 1.5V Buffer	t_{EN}, t_{DIS}, t_{BUF}	—	0.20	—	0.20	ns
LVCMOS18_out	Output Configured as 1.8V Buffer	t_{EN}, t_{DIS}, t_{BUF}	—	0.00	—	0.00	ns
LVCMOS25_out	Output Configured as 2.5V Buffer	t_{EN}, t_{DIS}, t_{BUF}	—	0.10	—	0.10	ns
LVCMOS33_out	Output Configured as 3.3V Buffer	t_{EN}, t_{DIS}, t_{BUF}	—	0.20	—	0.20	ns
PCI_out	Output Configured as PCI Compatible Buffer	t_{EN}, t_{DIS}, t_{BUF}	—	0.20	—	0.20	ns
Slow Slew	Output Configured for Slow Slew Rate	t_{EN}, t_{BUF}	—	1.00	—	1.00	ns

Note: Internal Timing Parameters are not tested and are for reference only. Refer to the timing model in this data sheet for further details.
Timing v.0.8

Boundary Scan Waveforms and Timing Specifications

Symbol	Parameter	Min.	Max.	Units
t_{BTCP}	TCK [BSCAN test] clock cycle	40	—	ns
t_{BTCH}	TCK [BSCAN test] pulse width high	20	—	ns
t_{BTCL}	TCK [BSCAN test] pulse width low	20	—	ns
t_{BTSU}	TCK [BSCAN test] setup time	8	—	ns
t_{BTH}	TCK [BSCAN test] hold time	10	—	ns
t_{BRF}	TCK [BSCAN test] rise and fall time	50	—	mV/ns
t_{BTCO}	TAP controller falling edge of clock to valid output	—	10	ns
t_{BTOZ}	TAP controller falling edge of clock to data output disable	—	10	ns
t_{BTVO}	TAP controller falling edge of clock to data output enable	—	10	ns
t_{BTCPSU}	BSCAN test Capture register setup time	8	—	ns
t_{BTCPH}	BSCAN test Capture register hold time	10	—	ns
t_{BTUCO}	BSCAN test Update reg, falling edge of clock to valid output	—	25	ns
t_{BTUOZ}	BSCAN test Update reg, falling edge of clock to output disable	—	25	ns
t_{BTUOV}	BSCAN test Update reg, falling edge of clock to output enable	—	25	ns

ispMACH 4000ZE Power Supply and NC Connections[1] (Cont.)

Signal	132 ucBGA[3]	144 csBGA[3]	144 TQFP[2]
VCC	M1, M7, A12, B5	H5, H8, E8, E5	36, 57, 108, 129
VCCO0 VCCO (Bank 0)	B1, H4, L2, J5, A4	E4, F4, G4, J5, D5	3, 19, 34, 47, 136
VCCO1 VCCO (Bank 1)	K9, L12, F12, D9, C7	J8, H9, G9, F9, D8	64, 75, 91, 106, 119
GND	E5, E8, H5, H8	F6, G6, G7, F7	1, 37, 73, 109
GND (Bank 0)	E2, H2, M4, B7, B3	G5, H4, H6, E6, F5	10, 18[4], 27, 46, 127, 137
GND (Bank 1)	L7, J9, H12, E9, A9	H7, J9, G8, F8, E7	55, 65, 82, 90[4], 99, 118
NC	—	**4064ZE:** E4, B2, B1, D2, D3, E1, H1, H3, H2, L1, G4, M1, K3, M2, M4, L5, H7, L8, M8, L10, K9, M11, H9, L12, L11, J12, J11, H10, D10, F10, D12, B12, F9, A12, C10, B10, A9, B8, E6, B5, A5, C4, B3, A2 **4128ZE:** D2, D3, H2, M1, K3, M11, J12, J11, D12, A12, C10, A2	**4128ZE:** 17, 20, 38, 45, 72, 89, 92, 110, 117, 144 **4256ZE:** 18, 90

1. All grounds must be electrically connected at the board level. However, for the purposes of I/O current loading, grounds are associated with the bank shown.
2. Pin orientation follows the conventional order from pin 1 marking of the top side view and counter-clockwise.
3. Pin orientation A1 starts from the upper left corner of the top side view with alphabetical order ascending vertically and numerical order ascending horizontally.
4. For the LC4256ZE, pins 18 and 90 are no connects.

ispMACH 4032ZE and 4064ZE Logic Signal Connections: 48 TQFP

Pin Number	Bank Number	ispMACH 4032ZE	ispMACH 4064ZE
		GLB/MC/Pad	GLB/MC/Pad
1	-	TDI	TDI
2	0	A5	A8
3	0	A6	A10
4	0	A7	A11
5	0	GND (Bank 0)	GND (Bank 0)
6	0	VCCO (Bank 0)	VCCO (Bank 0)
7	0	A8	B15
8	0	A9	B12
9	0	A10	B10
10	0	A11	B8
11	-	TCK	TCK
12	-	VCC	VCC
13	-	GND	GND
14	0	A12	B6
15	0	A13	B4
16	0	A14	B2
17	0	A15	B0
18	0	CLK1/I	CLK1/I
19	1	CLK2/I	CLK2/I
20	1	B0	C0
21	1	B1	C1
22	1	B2	C2
23	1	B3	C4
24	1	B4	C6
25	-	TMS	TMS
26	1	B5	C8
27	1	B6	C10
28	1	B7	C11
29	1	GND (Bank 1)	GND (Bank 1)
30	1	VCCO (Bank 1)	VCCO (Bank 1)
31	1	B8	D15
32	1	B9	D12
33	1	B10	D10
34	1	B11	D8
35	-	TDO	TDO
36	-	VCC	VCC
37	-	GND	GND
38	1	B12	D6
39	1	B13	D4
40	1	B14	D2
41	1	B15/GOE1	D0/GOE1
42	1	CLK3/I	CLK3/I

ispMACH 4064ZE Logic Signal Connections: 64 ucBGA

Ball Number	Bank Number	GLB/MC/Pad
A1	-	TDI
B1	0	A8
B2	0	A10
B3	0	A11
GND*	0	GND (Bank 0)
C1	0	A12
C3	0	VCCO (Bank 0)
C2	0	B15
D1	0	B14
D2	0	B13
D3	0	B12
E1	0	B11
E2	0	B10
E3	0	B9
F1	0	B8
F2	-	TCK
E4	-	VCC
GND*	-	GND
H2	0	B6
H1	0	B5
G1	0	B4
GND*	0	GND (Bank 0)
F3	0	VCCO (Bank 0)
G2	0	B3
G3	0	B2
H3	0	B0
G4	0	CLK1/I
F4	1	CLK2/I
H4	1	C0
H5	1	C1
G5	1	C2
H6	1	C4
H7	1	C5
H8	1	C6
G8	-	TMS
G7	1	C8
G6	1	C10
F8	1	C11
GND*	1	GND (Bank 1)
F7	1	C12
F6	1	VCCO (Bank 1)
F5	1	D15
E8	1	D14

ispMACH 4064ZE, 4128ZE and 4256ZE Logic Signal Connections: 100 TQFP (Cont.)

Pin Number	Bank Number	LC4064ZE	LC4128ZE	LC4256ZE
		GLB/MC/Pad	GLB/MC/Pad	GLB/MC/Pad
42	1	C1	E2	I6
43	1	C2	E4	I10
44	1	C3	E6	I12
45	1	VCCO (Bank 1)	VCCO (Bank 1)	VCCO (Bank 1)
46	1	GND (Bank 1)	GND (Bank 1)	GND (Bank 1)
47	1	C4	E8	J2
48	1	C5	E10	J6
49	1	C6	E12	J10
50	1	C7	E14	J12
51	-	GND	GND	GND
52	-	TMS	TMS	TMS
53	1	C8	F0	K12
54	1	C9	F2	K10
55	1	C10	F4	K6
56	1	C11	F6	K2
57	1	GND (Bank 1)	GND (Bank 1)	GND (Bank 1)
58	1	C12	F8	L12
59	1	C13	F10	L10
60	1	C14	F12	L6
61	1	C15	F13	L4
62*	1	I	I	I
63	1	VCCO (Bank 1)	VCCO (Bank 1)	VCCO (Bank 1)
64	1	D15	G14	M4
65	1	D14	G12	M6
66	1	D13	G10	M10
67	1	D12	G8	M12
68	1	GND (Bank 1)	GND (Bank 1)	GND (Bank 1)
69	1	D11	G6	N2
70	1	D10	G5	N6
71	1	D9	G4	N10
72	1	D8	G2	N12
73*	1	I	I	I
74	-	TDO	TDO	TDO
75	-	VCC	VCC	VCC
76	-	GND	GND	GND
77*	1	I	I	I
78	1	D7	H13	O12
79	1	D6	H12	O10
80	1	D5	H10	O6
81	1	D4	H8	O2
82	1	GND (Bank 1)	GND (Bank 1)	GND (Bank 1)

ispMACH 4064ZE, 4128ZE and 4256ZE Logic Signal Connections: 100 TQFP (Cont.)

Pin Number	Bank Number	LC4064ZE	LC4128ZE	LC4256ZE
		GLB/MC/Pad	GLB/MC/Pad	GLB/MC/Pad
83	1	VCCO (Bank 1)	VCCO (Bank 1)	VCCO (Bank 1)
84	1	D3	H6	P12
85	1	D2	H4	P10
86	1	D1	H2	P6
87	1	D0/GOE1	H0/GOE1	P2/GOE1
88	1	CLK3/I	CLK3/I	CLK3/I
89	0	CLK0/I	CLK0/I	CLK0/I
90	-	VCC	VCC	VCC
91	0	A0/GOE0	A0/GOE0	A2/GOE0
92	0	A1	A2	A6
93	0	A2	A4	A10
94	0	A3	A6	A12
95	0	VCCO (Bank 0)	VCCO (Bank 0)	VCCO (Bank 0)
96	0	GND (Bank 0)	GND (Bank 0)	GND (Bank 0)
97	0	A4	A8	B2
98	0	A5	A10	B6
99	0	A6	A12	B10
100	0	A7	A14	B12

* This pin is input only.

ispMACH 4128ZE Logic Signal Connections: 132 ucBGA (Cont.)

Ball Number	Bank Number	GLB/MC/Pad
M5	0	D5
J6	0	D4
K6	0	D2
L6	0	D1
M6	0	D0
K7	0	CLK1/I
L7	1	GND (Bank 1)
J7	1	CLK2/I
M7	-	VCC
K8	1	E0
L8	1	E1
M8	1	E2
J8	1	E4
L9	1	E5
M9	1	E6
K9	1	VCCO (Bank 1)
J9	1	GND (Bank 1)
L10	1	E8
K10	1	E9
M10	1	E10
L11	1	E12
K12	1	E13
M11	1	E14
GND*	-	GND
M12	-	TMS
L12	1	VCCO (Bank 1)
K11	1	F0
J10	1	F1
H9	1	F2
J12	1	F4
J11	1	F5
H10	1	F6
H12	1	GND (Bank 1)
G9	1	F8
H11	1	F9
F9	1	F10
G12	1	F12
G11	1	F13
G10	1	F14
F12	1	VCCO (Bank 1)
F10	1	G14
F11	1	G13
E11	1	G12
E10	1	G10

ispMACH 4128ZE Logic Signal Connections: 132 ucBGA (Cont.)

Ball Number	Bank Number	GLB/MC/Pad
D10	1	G9
E12	1	G8
E9	1	GND (Bank 1)
D12	1	G6
D11	1	G5
C12	1	G4
C10	1	G2
C11	1	G1
B11	1	G0
D9	1	VCCO (Bank 1)
B12	-	TDO
A12	-	VCC
GND*	-	GND
A10	1	H14
A11	1	H13
B10	1	H12
C9	1	H10
D8	1	H9
C8	1	H8
A9	1	GND (Bank 1)
C7	1	VCCO (Bank 1)
B9	1	H6
B8	1	H5
D7	1	H4
A8	1	H2
A7	1	H1
B6	1	H0/GOE1
C6	1	CLK3/I
B7	0	GND (Bank 0)
D6	0	CLK0/I
B5	-	VCC
A6	0	A0/GOE0
C5	0	A1
B4	0	A2
A5	0	A4
C4	0	A5
D5	0	A6
A4	0	VCCO (Bank 0)
B3	0	GND (Bank 0)
D4	0	A8
A3	0	A9
C3	0	A10
B2	0	A12
C2	0	A13

ispMACH 4128ZE Logic Signal Connections: 132 ucBGA (Cont.)

Ball Number	Bank Number	GLB/MC/Pad
A2	0	A14

* All bonded core grounds are connected to the following four balls, E5, E8, H5 and H8.

Figure 20. Mark Format for 64 ucBGA and 132 ucBGA Packages

Dual Mark **Single Mark**

Lead-Free Packaging

Commercial

Device	Part Number	Macrocells	Voltage	t_{PD}	Package	Pin/Ball Count	I/O	Grade
LC4032ZE	LC4032ZE-4TN48C	32	1.8	4.4	Lead-Free TQFP	48	32	C
	LC4032ZE-5TN48C	32	1.8	5.8	Lead-Free TQFP	48	32	C
	LC4032ZE-7TN48C	32	1.8	7.5	Lead-Free TQFP	48	32	C
	LC4032ZE-4MN64C	32	1.8	4.4	Lead-Free csBGA	64	32	C
	LC4032ZE-5MN64C	32	1.8	5.8	Lead-Free csBGA	64	32	C
	LC4032ZE-7MN64C	32	1.8	7.5	Lead-Free csBGA	64	32	C
LC4064ZE	LC4064ZE-4TN48C	64	1.8	4.7	Lead-Free TQFP	48	32	C
	LC4064ZE-5TN48C	64	1.8	5.8	Lead-Free TQFP	48	32	C
	LC4064ZE-7TN48C	64	1.8	7.5	Lead-Free TQFP	48	32	C
	LC4064ZE-4TN100C	64	1.8	4.7	Lead-Free TQFP	100	64	C
	LC4064ZE-5TN100C	64	1.8	5.8	Lead-Free TQFP	100	64	C
	LC4064ZE-7TN100C	64	1.8	7.5	Lead-Free TQFP	100	64	C
	LC4064ZE-4MN64C	64	1.8	4.7	Lead-Free csBGA	64	48	C
	LC4064ZE-5MN64C	64	1.8	5.8	Lead-Free csBGA	64	48	C
	LC4064ZE-7MN64C	64	1.8	7.5	Lead-Free csBGA	64	48	C
	LC4064ZE-4MN144C	64	1.8	4.7	Lead-Free csBGA	144	64	C
	LC4064ZE-5MN144C	64	1.8	5.8	Lead-Free csBGA	144	64	C
	LC4064ZE-7MN144C	64	1.8	7.5	Lead-Free csBGA	144	64	C
LC4128ZE	LC4128ZE-5TN100C	128	1.8	5.8	Lead-Free TQFP	100	64	C
	LC4128ZE-7TN100C	128	1.8	7.5	Lead-Free TQFP	100	64	C
	LC4128ZE-5TN144C	128	1.8	5.8	Lead-Free TQFP	144	96	C
	LC4128ZE-7TN144C	128	1.8	7.5	Lead-Free TQFP	144	96	C
	LC4128ZE-5UMN132C	128	1.8	5.8	Lead-Free ucBGA	132	96	C
	LC4128ZE-7UMN132C	128	1.8	7.5	Lead-Free ucBGA	132	96	C
	LC4128ZE-5MN144C	128	1.8	5.8	Lead-Free csBGA	144	96	C
	LC4128ZE-7MN144C	128	1.8	7.5	Lead-Free csBGA	144	96	C
LC4256ZE	LC4256ZE-5TN100C	256	1.8	5.8	Lead-Free TQFP	100	64	C
	LC4256ZE-7TN100C	256	1.8	7.5	Lead-Free TQFP	100	64	C
	LC4256ZE-5TN144C	256	1.8	5.8	Lead-Free TQFP	144	96	C
	LC4256ZE-7TN144C	256	1.8	7.5	Lead-Free TQFP	144	96	C
	LC4256ZE-5MN144C	256	1.8	5.8	Lead-Free csBGA	144	108	C
	LC4256ZE-7MN144C	256	1.8	7.5	Lead-Free csBGA	144	108	C

Revision History

Date	Version	Change Summary
April 2008	01.0	Initial release.
July 2008	01.1	Updated Features bullets.
		Updated typical Hysteresis voltage.
		Updated Power Guard for Dedicated Inputs section.
		Updated DC Electrical Characteristics table.
		Updated Supply Current table.
		Updated I/O DC Electrical Characteristics table and note 2.
		Updated ispMACH 4000ZE Timing Model.
		Added new parameters for the Internal Oscillator.
		Updated ORP Reference table.
		Updated Power Supply and NC Connections table.
		Updated 100 TQFP Logic Signal Connections table with LC4128ZE and 4256ZE.
		Updated 144 csBGA Logic Signal Connections table with LC4128ZE and 4256ZE.
		Added 144 TQFP Logic Signal Connections table.
August 2008	01.2	Data sheet status changed from advance to final.
		Updated Supply Current table.
		Updated External Switching Characteristics.
		Updated Internal Timing Parameters.
		Updated Power Consumption graph and Power Estimation Coefficients table.
		Updated Ordering Information mark format example.
December 2008	01.3	Updated ispMACH 4000ZE Family Selection Guide table to include 64-ball ucBGA and 132-ball ucBGA packages.
		Updated ispMACH 4000ZE Power Supply and NC Connections table to include 64-ball ucBGA and 132-ball ucBGA packages.
		Added Logic Signal Connections tables for 64-ball ucBGA and 132-ball ucBGA packages.
		Updated Part Number Description diagram for 64-ball ucBGA and 132-ball ucBGA packages.
		Updated Ordering Information tables for 64-ball ucBGA and 132-ball ucBGA packages.
May 2009	01.4	Correction to t_{CW}, t_{GW}, t_{WIR} and f_{MAX} parameters in External Switching Characteristics table.
June 2011	01.5	Added copper bond package part numbers.
		Added footnote 4 to Absolute Maximum Ratings.
February 2012	01.6	Updated document with new corporate logo.
February 2012	01.7	Removed copper bond packaging information. Refer to PCN 04A-12 for further information.
		Updated topside marks with new logos in the Ordering Information section.